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# HL6722G

AlGaInP Laser Diode

# HITACHI

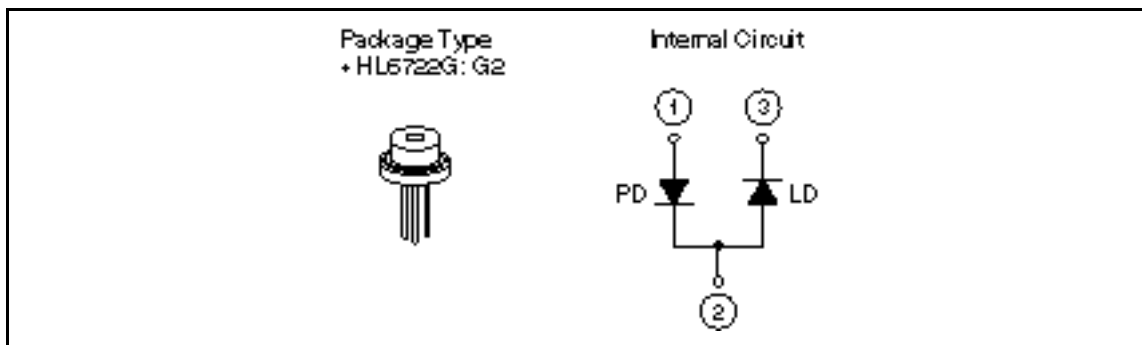
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## Description

The HL6722G is a 0.67  $\mu\text{m}$  band AlGaInP index-guided laser diode with a multi-quantum well(MQW) structure. It is suitable as a light source for barcode scanner, and various other types of optical equipment. Hermetic sealing of the package assures high reliability.

## Features

- Visible light output at wavelengths up to 680 nm
- Continuous operating output: 5 mW CW
- Low voltage operation: 2.7 V Max
- Low current operation: 32 mA Typ
- Single longitudinal mode
- Built-in monitor photodiode



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## HL6722G

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### Absolute Maximum Ratings ( $T_C = 25^\circ\text{C}$ )

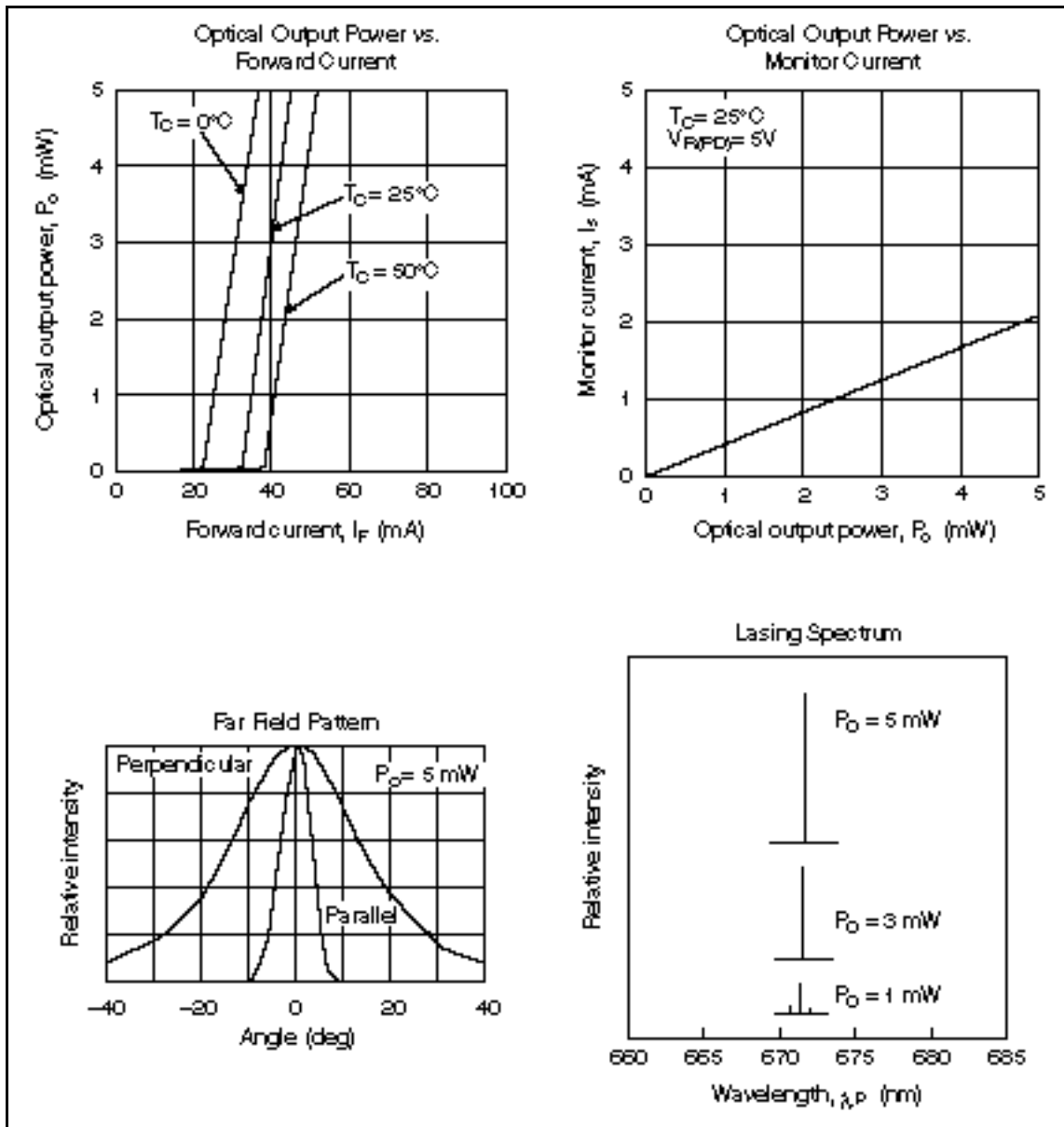
Item	Symbol	Rated Value	Unit
Optical output power	$P_O$	5	mW
Pulse optical output power	$P_{O(\text{pulse})}$	6* <sup>1</sup>	mW
LD reverse voltage	$V_{R(\text{LD})}$	2	V
PD reverse voltage	$V_{R(\text{PD})}$	30	V
Operating temperature	$T_{opr}$	-10 to +50	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-40 to +85	$^\circ\text{C}$

Note: 1. Maximum 50% duty cycle, maximum 1  $\mu\text{s}$  pulse width

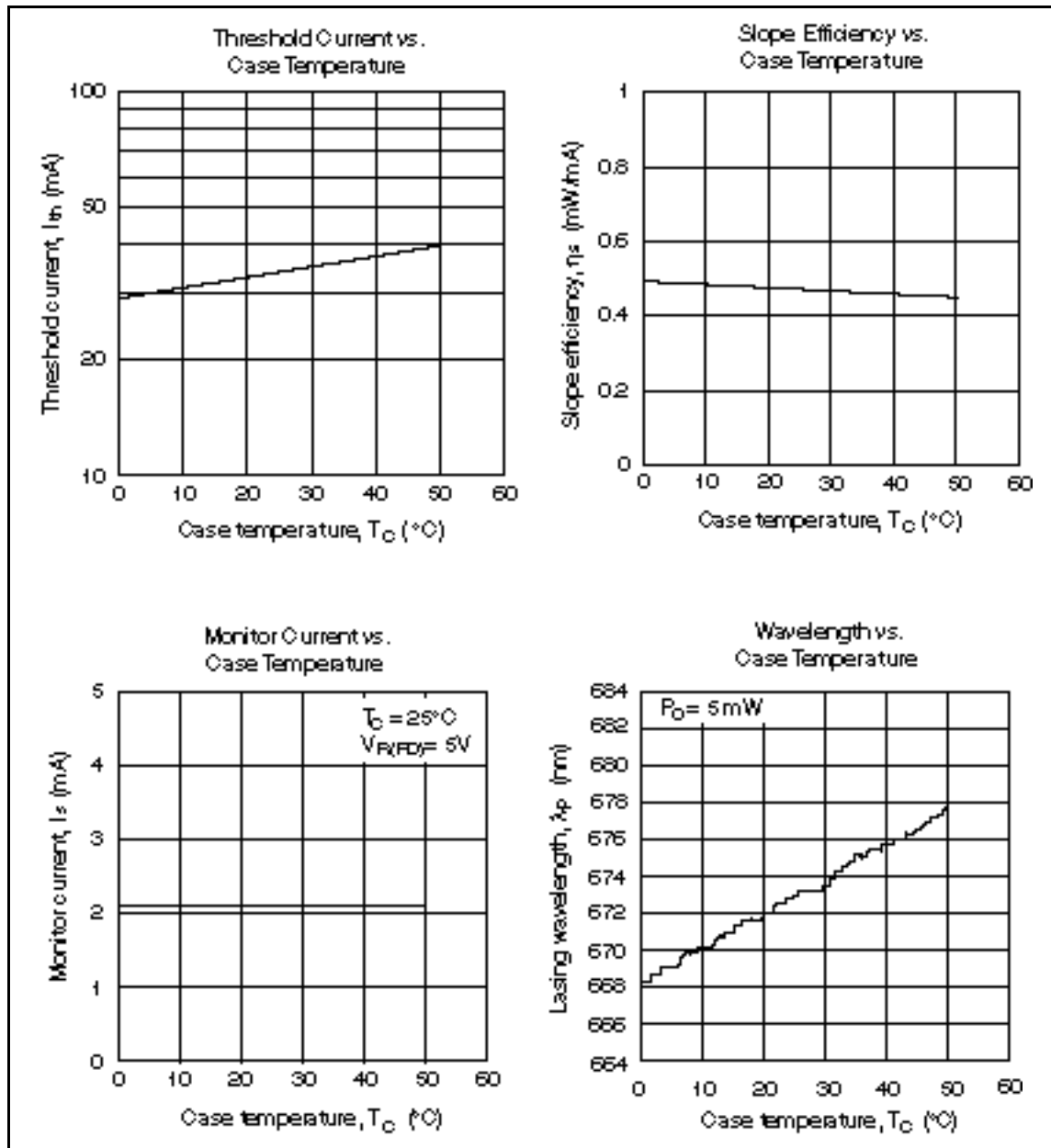
### Optical and Electrical Characteristics ( $T_C = 25^\circ\text{C}$ )

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Optical output power	$P_O$	5	—	—	mW	Kink free
Threshold current	$I_{th}$	20	32	55	mA	
Slope efficiency		0.3	0.5	0.7	mW/mA	$3 \text{ mW}/I_{(4 \text{ mW})} - I_{(1 \text{ mW})}$
LD operating current	$I_{op}$	—	42	70	mA	$P_O = 5 \text{ mW}$
LD operating voltage	$V_{op}$	—	—	2.7	V	$P_O = 5 \text{ mW}$
Lasing wavelength	$\lambda$	660	670	680	nm	$P_O = 5 \text{ mW}$
Beam divergence (parallel)	//	5	8	11	deg.	$P_O = 5 \text{ mW}$
Beam divergence (perpendicular)		22	30	38	deg.	$P_O = 5 \text{ mW}$
Monitor current	$I_s$	1	—	3	mA	$P_O = 5 \text{ mW}, V_R = 5 \text{ V}$

Typical Characteristic Curves



Typical Characteristic Curves (cont)



Typical Characteristic Curves (cont)

